

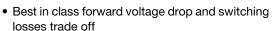
FRED Pt® Gen 5, Ultrafast Rectifier Diode, 600 V, 600 A



PRIMARY CHARACTERISTICS						
I _{F(AV)} at 77 °C (per module)	600 A					
V_{R}	600 V					
Q _{rr} (typical)	800 nC					
t _{rr}	78 ns					
Type	Modules - diode, FRED Pt®					
Package	TO-244					
Circuit configuration	Two diodes common cathode					

FEATURES

Ultrafast and optimized Q_{rr}





- Optimized for high speed operation
- 175 °C maximum operation junction temperature
- UL approved file E222165
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

BENEFITS

- · Reduced RFI and EMI
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses the FRED Pt® Gen 5 is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters.

These devices are also ideally suited for HF welding, power converters, and other applications where switching losses are significant portion of the total losses.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Cathode to anode voltage	V _R		600	V	
		T _C = 25 °C	505		
Continuous forward current per diode	I _{F(DC)}	T _C = 85 °C	359		
		T _C = 106 °C	271	Α	
Non-repetitive single pulse forward current per diode	I _{FSM}	T _C = 25 °C	2200		
Manian and a superior distribution and distribution of the superior distri		T _C = 25 °C	938	w	
Maximum power dissipation per diode	P_D	T _C = 106 °C	431	VV	
Storage temperature range	T _{Stg}		-40 to +150	°C	
Operating junction temperature range	TJ		-40 to +175	°C	

ELECTRICAL SPECIFICATIONS PER LEG (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage	V_{BR}	$I_R = 400 \mu A$	600	-	-		
Forward voltage V _{FM}	V	I _F = 300 A	-	1.34	1.70	v	
		$I_F = 600 \text{ A}$	-	1.52	2.25		
	I _F = 300 A, T _J = 150 °C	-	1.11	-			
		I _F = 600 A, T _J = 150 °C	-	1.35	-		
Reverse leakage current	I _{RM}	T _J = 150 °C, V _R = 600 V		0.4	1.0	mA	
Series inductance	L _S	From top of terminal hole to mounting plane	-	5	-	nΗ	
Maximum junction capacitance per leg	C _T	V _{DC} = 5 V, f = 1 MHz, 25 °C		1.8	nF		



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS			TYP.	MAX.	UNITS
Reverse recovery time	+	T _J = 25 °C		-	78	-	20
neverse recovery time	t _{rr}	T _J = 125 °C		-	193	-	ns
Dook was a van a summant		T _J = 25 °C	$I_F = 50 \text{ A},$ $dI_F/dt = 200 \text{ A/}\mu\text{s},$	-	9.0	-	Α
Peak recovery current	IRRM	T _J = 125 °C	$V_{R} = 300 \text{ V}$	-	25	-	^
Deviage receives above	0	T _J = 25 °C		-	880	-	nC
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	4000	-	IIC

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	MIN.	TYP.	MAX.	UNITS	
Thermal resistance,	per leg	В	-	-	0.16		
junction to case	per module	R _{thJC}	-	-	0.08	°C/W	
Thermal resistance, case	to heatsink	R _{thCS}	-	0.10	-		
Weight			-	68	-	g	
			-	2.4	-	oz.	
Mounting torque			30 (3.4)	-	40 (4.6)		
Mounting torque center hole			12 (1.4)	-	18 (2.1)	lbf · in (N · m)	
Terminal torque			30 (3.4)	-	40 (4.6)	(14)	
Vertical pull			=	-	80	- lbf ⋅ in	
2" lever pull			=	-	35	ioi · In	
Case style			TO-244				

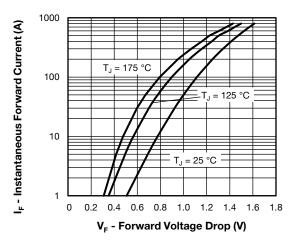


Fig. 1 - Typical Forward Voltage Drop vs. Instantaneous Forward Current (Per Diode)

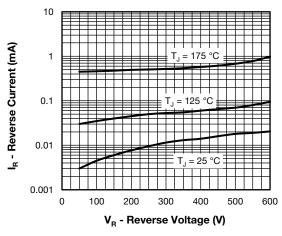


Fig. 2 - Typical Reverse Current vs. Reverse Voltage (Per Diode)

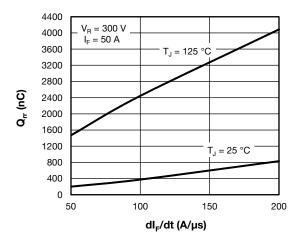


Fig. 3 - Typical Reverse Recovery Charge vs dl_F/dt (Per Diode)

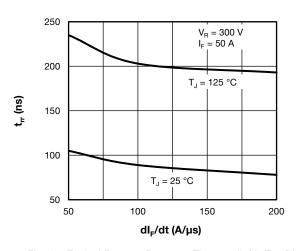


Fig. 4 - Typical Reverse Recovery Time vs dl_F/dt (Per Diode)

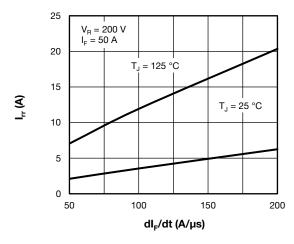


Fig. 5 - Typical Reverse Recovery Current vs dl_F/dt (Per Diode)

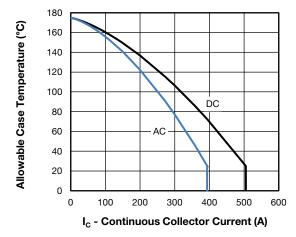


Fig. 6 - Maximum Continuous Forward Current vs.

Case Temperature



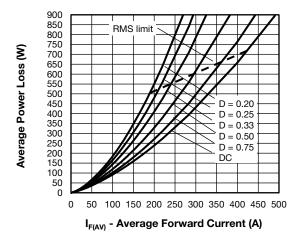


Fig. 7 - Average Power Loss vs. Average Forward Current (Forward Power Loss Characteristics)

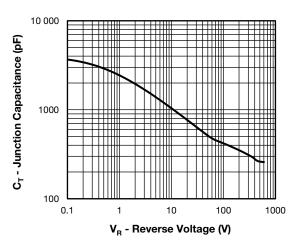


Fig. 8 - Typical Junction Capacitance vs. Reverse Voltage

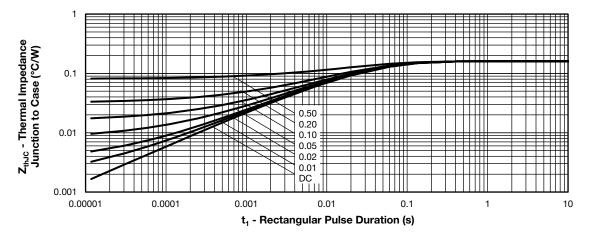


Fig. 9 - Z_{thJC} Maximum Thermal Impedance Junction to Case vs. t_1 Rectangular Pulse Duration

ORDERING INFORMATION TABLE

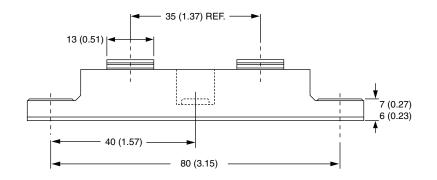
Device code	vs-vs	5HD	600	С	w	60	
	1	2	3	4	5	6	•
	1 -	Vish	ay Semi	iconduct	tors pro	duct	
	2 -	5HD	= high s	speed F	RED Pt	® Gen 5	5
	3 -	Curr	ent ratin	g (600 =	= 600 A)	
	4 -	Circ	uit config	guration	:		
		C = 1	two diod	les com	mon cat	thode	
	5 -	W =	TO-244	wire bo	ndable	not isola	ated
	6 - Voltage rating (60 = 600 V)						

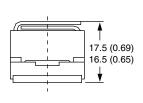


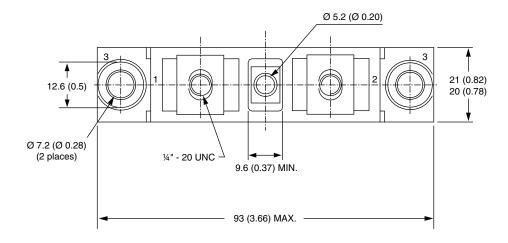
CIRCUIT CONFIGURATION					
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING			
Two diodes common cathode	С	Lug Lug terminal terminal anode 1 anode 2 Base common cathode			

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95021

DIMENSIONS in millimeters (inches)









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Vishay

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